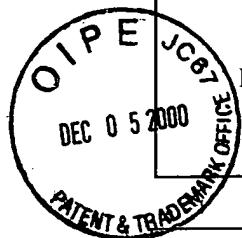


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OFFICE OF PETITIONS

PTO-1449 (Modified)		ATTY. DOCKET NO. RA001C10	SERIAL NUMBER 09/514,872
U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		APPLICANT(S) FARMWALD ET AL.	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		FILING DATE FEBRUARY 28, 2000	GROUP ART UNIT 2781 2181



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EXAMINER INITIALS	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE
✓per D. Novak	4,633,735	05/05/87	Novak, et. al	—	—	
✓per D. Hashimoto	5,684,753	11/04/97	Hashimoto, et al	—	—	
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✓per D. Ikeda	Ikeda, Hiroaki et al., "100 MHz Serial Access Architecture for 4Md Field Memory," Symposium of VLSI Circuits, Digest of Technical Papers, pp. 11-12 (Jun. 1990)
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EXAMINER <i>Glenn Ahne</i>	DATE CONSIDERED <i>1/12/2001</i>
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DA	Tomoji Takada et al., "A Video Codec LSI for High-Definition TV Systems with One-Transistor DRAM Line Memories," IEEE Journal of Solid-State Circuits, Vol. 24, No. 6, pp. 1656-1659 (Dec. 1989)
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EXAMINER	Glenn Auve	DATE CONSIDERED	1/12/2001
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